

MN3102 CMOS Clock Generator / Driver for Low Voltage Operation BBD	$V_{DD} = -0.3 \sim +12V$ $V_I = -0.3 \sim V_{DD} + 0.3V$ $V_O = -0.3 \sim V_{DD} + 0.3V$ $P_D = 200mW$ $T_{opr} = -10 \sim +70^\circ C$ $T_{stg} = -30 \sim +125^\circ C$	Supply Current	I _{DD}	Without load Clock output 40kHz	0.5	mA
		Power Consumption	P _{tot}		2.5	mW
		"H" Level Input Voltage (OX1)	V _{IH}		V _{DD} - 1	V
		"L" Level Input Voltage (OX1)	V _{IL}		0	V
		"H" Level Output Current (OX2)	I _{OH1}	V _O = 4V	0.5	mA
		"L" Level Output Current (OX2)	I _{OL1}	V _O = 1V	0.4	mA
		"H" Level Output Current (OX3)	I _{OH2}	V _O = 4V	0.7	mA
		"L" Level Output Current (OX3)	I _{OL2}	V _O = 1V	1	mA
		Operating Condition	I _{OH3}	V _O = 4V	5	mA
			I _{OL3}	V _O = 1V	5	mA
	V _{DD} = 5V	Output Voltage (V _G G OUT)	V _G G (OUT)	4.67	V	

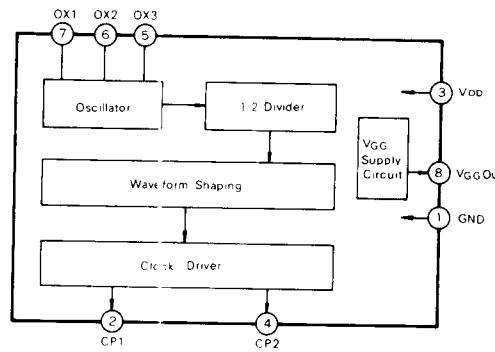
* V_G voltage supply for Matsushita low voltage operation BBDS.
The voltage might not be suitable for other maker's.

DIGITAL MONOLITHIC INTEGRATED CIRCUITS (MOS)

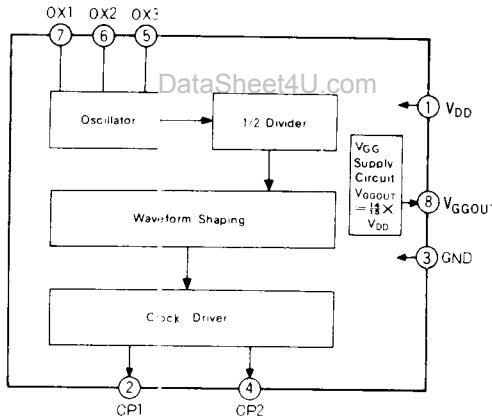
MOS IC, LSI

Block Diagram

MN3101 (Package L-9, 8-Lead Plastic DIL)



MN3102 (Package L-9, 8-Lead Plastic DIL)



MN133 (Package L-12, 14-Lead Plastic DIL)

